

1. Record Nr.	UNINA9910699314003321
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Titolo	Junction-to-case thermal resistance of a silicon carbide bipolar junction transistor measured [[electronic resource] /] / Janis M. Niedra
Pubbl/distr/stampa	Cleveland, Ohio : , : National Aeronautics and Space Administration, Glenn Research Center, , [2006]
Descrizione fisica	1 online resource (11 pages) : illustrations
Collana	NASA/CR ; ; 2006-214258
Soggetti	Junction transistors Temperature measurement Bipolar transistors Electric potential Pulse amplitude Thermal resistance Silicon carbides
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Title from title screen (viewed on May 16, 2012). "November 2006." "Preparing organization, QSS Group, Inc."--Rept. documentation p.
Nota di bibliografia	Includes bibliographical references (page 11).